- Very Low Power Consumption . . . 2 mW Typ at $V_{DD} = 5 \text{ V}$
- Capable of Operation in Astable Mode
- **CMOS Output Capable of Swinging Rail to**
- **High Output-Current Capability** Sink 100 mA Typ Source 10 mA Typ
- Output Fully Compatible With CMOS, TTL, and MOS
- **Low Supply Current Reduces Spikes During Output Transitions**
- High-Impedance Inputs . . . $10^{12} \Omega$ Typ
- Single-Supply Operation From 1 V to 18 V
- Functionally Interchangeable With the NE556; Has Same Pinout

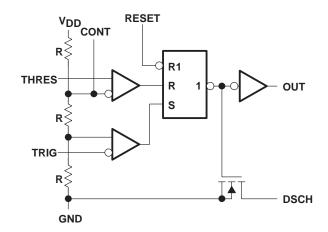
description

The TLC552 is a dual monolithic timing circuit fabricated using TI LinCMOS™ process, which provides full compatibility with CMOS, TTL, and MOS logic and operation at frequencies up to 2 MHz. Accurate time delays and oscillations are possible with smaller, less-expensive timing capacitors than the NE555 because of the high input impedance. Power consumption is low across the full range of power supply voltages.

Like the NE556, the TLC552 has a trigger level approximately one-third of the supply voltage and a threshold level approximately two-thirds of the supply voltage. These levels can be altered by use of the control voltage terminal. When the trigger input falls below the trigger level, the flip-flop is set and the output goes high. If the trigger input is above the trigger level and the threshold input is above the threshold level, the flip-flop is reset and

D OR N PACKAGE (TOP VIEW) DSCH I Λ^{DD} THRES | 13 DSCH CONT [12 THRES **TIMER** 3 RESET [11 CONT **TIMER** 10 ∏ RESET #2 OUT [TRIG [6 9∏OUT GND [8 TRIG

functional block diagram (each timer)



RESET can override TRIG and THRES. TRIG can override THRES.

AVAILABLE OPTIONS

SYMBO	LIZATION	OPERATING	
DEVICE	PACKAGE SUFFIX	TEMPERATURE RANGE	V _T max at 25°C
TLC552C	D,N	0°C to 70°C	3.8 mV

The D packages are available taped and reeled. Add the suffix R to the device type when ordering (i.e., TLC552CDR).

the output is low. The reset input can override all other inputs and can be used to initiate a new timing cycle. If the reset input is low, the flip-flop is reset and the output is low. Whenever the output is low, a low-impedance path is provided between the discharge terminal and ground.

While the CMOS output is capable of sinking over 100 mA and sourcing over 10 mA, the TLC552 exhibits greatly reduced supply-current spikes during output transitions. This minimizes the need for the large decoupling capacitors required by the NE556.

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description (continued)

These devices have internal electrostatic discharge (ESD) protection circuits that will prevent catastrophic failures at voltages up to 2000 V as tested under MIL-STD-883C, Method 3105.2. However, care should be exercised in handling these devices as exposure to ESD may result in a degradation of the device parametric performance.

All unused inputs should be tied to an appropriate logic level to prevent false triggering.

The TLC552C is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

RESET VOLTAGET	TRIGGER VOLTAGE†	THRESHOLD VOLTAGET	ОИТРИТ	DISCHARGE SWITCH		
< MIN	Irrelevant	Irrelevant	Low	On		
> MAX	< MIN	Irrelevant	High	Off		
> MAX	> MAX	> MAX	Low	On		
> MAX	> MAX	< MIN	As previously established			

[†] For conditions shown as MIN or MAX, use the appropriate value specified under electrical characteristics.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{DD} (see Note 1)	18 V
Input voltage range (any input)	– 0.3 V to V _{DD}
Sink current, DSCH or OUT	150 mĀ
Source current, OUT	15 mA
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range	0°C to 75°C
Storage temperature range	– 65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTES: 1. All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	GE POWER RATING DERATING FACTOR		ABOVE T _A
D	950 mW	7.6 mW/°C	25°C
N	1150 mW	9.2 mW/°C	25°C

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V _{DD}	1	18	V
Operating free-air temperature range, TA	0	70	°C



TLC552C

electrical characteristics at specified free-air temperature, $V_{DD} = 1 V$

PARAMETER	TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT
Threshold voltage level		25°C	0.475	0.67	0.85	V
Trifestioid voltage level		Full range	0.45		0.875	V
Threshold current		25°C		10		pА
The shou cullent		MAX		75		PΛ
Trigger voltage level		25°C	0.15	0.33	0.425	V
Trigger voltage level		Full range	0.1		1.45	V
Trigger current		25°C		10		pА
Inigger current		MAX		75		PΑ
Reset voltage level		25°C	0.4	0.7	1	V
Reset voltage level		Full range	0.3		1	V
Reset current		25°C		10		nΛ
Reset current		MAX		75		pА
Control voltage (open-circuit) as a percentage of supply voltage		MAX		66.7%		
Discharge switch on-state voltage	100	25°C		0.02	0.15	V
Discharge switch on-state voltage	Ι _Ο L = 100 μΑ	Full range			0.2	V
Discharge switch off-state current		25°C		0.1		nA
Discharge switch on-state current		MAX		0.5		TIA
Low-level output voltage	lo 100 uA	25°C		0.03	0.2	V
Low-level output voltage	I _{OL} = 100 μA	Full range			0.25	V
High lovel output voltage	10.17	25°C	0.6	0.98		V
High-level output voltage	ΙΟΗ = -10 μΑ	Full range	0.6			V
Supply current		25°C		30	200	
Supply current		Full range			300	μΑ

[†]Full range (MIN to MAX) is 0°C to 70°C.

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electrical characteristics at specified free-air temperature, V_{DD} = 2 V

PARAMETER	TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT	
Threshold voltage level		25°C	0.95	1.33	1.65	V	
Trireshold voltage level		Full range	0.85		1.75	V	
Threshold current		25°C		10		pА	
Threshold current		MAX		75		pΑ	
Trigger voltage level		25°C	0.4	0.67	0.95	V	
Trigger voltage level		Full range	0.3		1.05	V	
Trigger current		25°C		10		pА	
Ingger current		MAX		75		pΑ	
Reset voltage level		25°C	0.4	1.1	1.5	V	
Reset voltage level		Full range	0.3		1.8	V	
Reset current		25°C		10		m A	
Reset current		MAX		75		pΑ	
Control voltage (open-circuit) as a percentage of supply voltage		MAX		66.7%			
Discharge switch on-state voltage	la. 1 m A	25°C		0.03	0.2	V	
Discharge switch on-state voltage	I _{OL} = 1 mA	Full range			0.25	V	
Discharge switch off-state current		25°C		0.1		nA	
Discharge switch on-state current		MAX		0.5		IIA	
Low lovel output veltage	la. 1 m A	25°C		0.07	0.3	V	
Low-level output voltage	I _{OL} = 1 mA	Full range			0.35	V	
Lligh lovel output voltage	Jan. 200 u A	25°C	1.5	1.9		V	
High-level output voltage	ΙΟΗ = -300 μΑ	Full range	1.5			V	
Supply current		25°C		130	500		
Supply current		Full range			800	μΑ	

[†] Full range (MIN to MAX) is 0°C to 70°C.



TLC552C

electrical characteristics at specified free-air temperature, $V_{DD} = 5 \text{ V}$

PARAMETER	TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT
Threshold voltage level		25°C	2.8	3.3	3.8	V
Threshold voltage level		Full range	2.7		3.9	V
Threshold current		25°C		10		pА
Threshold current		MAX		75		PΑ
Trigger voltage level		25°C	1.36	1.66	1.96	V
Trigger voltage level		Full range	1.26		2.06	V
Trigger current		25°C		10		pА
Ingger current		MAX		75		PΛ
Reset voltage level		25°C	0.4	1.1	1.5	V
Neset voltage level		Full range	0.3		1.8	V
Reset current		25°C		10		pА
Neset current		MAX		75		PΑ
Control voltage (open-circuit) as a percentage of supply voltage		MAX		66.7%		
Discharge switch on-state voltage	la: - 10 mA	25°C		0.14	0.5	V
Discharge Switch on-State voltage	I _{OL} = 10 mA	Full range			0.6	V
Discharge switch off-state current		25°C		0.1		nA
Discharge Switch on-State current		MAX		0.5		ПА
	I _{OL} = 8 mA	25°C		0.21	0.4	
	IOL = 0 IIIA	Full range			0.5	
Low-level output voltage	I _{OL} = 5 mA	25°C		0.13	0.3	V
Low-level output voltage	IOL = 5 IIIA	Full range			0.4	V
	lo 2.2 m/	25°C		0.08	0.3	
	I _{OL} = 3.2 mA	Full range			0.35	
High-level output voltage	I _{OH} = -1 mA	25°C	4.1	4.8		V
i ingri-rever output voltage	IOH = - I IIIA	Full range	4.1			V
Supply current		25°C		340	700	μΑ
очрру синені 		Full range			1000	μΛ

[†] Full range (MIN to MAX) is 0°C to 70°C.

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electrical characteristics at specified free-air temperature, V_{DD} = 15 V

PARAMETER	TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT
Threshold voltage level		25°C	9.45	10	10.55	V
Trireshold voltage level		Full range	9.35		10.65	V
Threshold current		25°C		10		pА
The shou current		MAX		75		PΑ
Trigger voltage level		25°C	4.65	5	5.35	V
Trigger voltage level		Full range	4.55		5.45	V
Trigger current		25°C		10		pА
Thigger current		MAX		75		PA
Reset voltage level		25°C	0.4	1.1	1.5	V
Reset voltage level		Full range	0.3		1.8	V
Reset current		25°C		10		pА
Reset current		MAX		75		PΑ
Control voltage (open-circuit) as a percentage of supply voltage		MAX		66.7%		
Discharge quitab en etete valtage	la. 100 mA	25°C		0.77	1.7	V
Discharge switch on-state voltage	I _{OL} = 100 mA	Full range			1.8	V
Discharge quitab off state gurrent		25°C		0.1		nA
Discharge switch off-state current		MAX		0.5		IIA
	I _{OL} = 100 mA	25°C		1.28	3.2	
	IOC = 100 IIIA	Full range			3.6	
Low-level output voltage	lo. – 50 mA	25°C		0.63	1	V
Low-level output voltage	I _{OL} = 50 mA	Full range			1.3	V
	la. 10 m A	25°C		0.12	0.3	
	I _{OL} = 10 mA	Full range			0.4	
	I _{OH} = -10 mA	25°C	12.5	14.2		
	10H = - 10 IIIA	Full range	12.5			
High-level output voltage	la 5 m A	25°C	13.5	14.6		V
I rigit-level output voltage	I _{OH} = -5 mA	Full range	13.5			V
	lou - 1 m^	25°C	14.2	14.9		1
	I _{OH} = -1 mA	Full range	14.2			
Supply current		25°C		0.72	1.2	mΛ
Supply current		Full range			1.6	mA

[†] Full range (MIN to MAX) is 0°C to 70°C.

TLC552C

electrical characteristics at specified free-air temperature, V_{DD} = 18 V

PARAMETER	TEST CONDITIONS	T _A †	MIN	TYP	MAX	UNIT
Threshold voltage level		25°C	11.4	12	12.6	V
Tilleshold voltage level		Full range	10.9		12.7	٧
Threshold current		25°C		10		pА
Threshold current		MAX		75		PΑ
Trigger voltage level		25°C	5.6	6	6.4	V
rrigger voltage level		Full range	5.5		6.5	V
Trigger current		25°C		10		pА
ringger current		MAX		75		ÞΑ
Reset voltage level		25°C	0.4	1.1	1.5	V
Reset voltage level		Full range	0.3		1.8	V
Reset current		25°C		10		n 1
Reset current		MAX		75		pА
Control voltage (open-circuit) as a percentage of supply voltage		MAX		66.7%		
Discharge quitab en etate voltage	lo 100 mA	25°C		0.72	1.5	V
Discharge switch on-state voltage	I _{OL} = 100 mA	Full range			1.6	٧
Discharge switch off-state current		25°C		0.1		nA
Discharge Switch on-state current		MAX		0.5		ПА
Low-level output voltage	la 2.2 m/	25°C		0.04	0.3	V
Low-level output voltage	$I_{OL} = 3.2 \text{ mA}$	Full range			0.35	V
High-level output voltage	1011 - 1 mA	25°C	17.3	17.9		V
i ingri-rever output voltage	$I_{OH} = -1 \text{ mA}$	Full range	17.3			l ^v
Cupply gurrant		25°C		0.84	1.2	mA
Supply current		Full range			1.6	mA

[†] Full range (MIN to MAX) is 0°C to 70°C.

operating characteristics, V_{DD} = 5 V, T_A = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
Initial error of timing interval‡	$V_{DD} = 5 \text{ V to } 15 \text{ V},$	$R_A = R_B = 1 \text{ k}\Omega \text{ to } 100 \text{ k}\Omega,$		1%	3%	
Supply voltage sensitivity of timing interval	$C_T = 0.1 \mu\text{F},$ See Note 2			0.1	0.5	%/V
Output pulse rise time	D. 40 MO	C: 10 pF		20	75	
Output pulse fall time	$R_L = 10 M\Omega$,	C _L = 10 pF		15	60	ns
Maximum frequency in astable mode	$R_A = 470 \Omega,$ $C_T = 200 pF,$	$R_B = 200 \Omega$, See Note 2	1.2	2.8	·	MHz

[‡] Timing interval error is defined as the difference between the measured value and the nominal value of a random sample. NOTE 2: R_A, R_B, and C_T are as defined in Figure 1.



APPLICATION INFORMATION

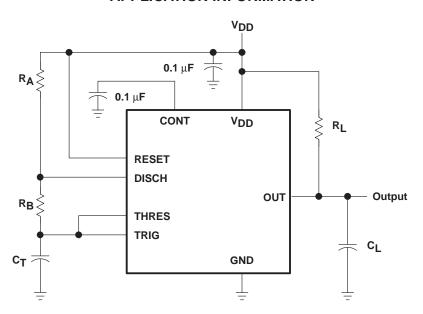


Figure 1. Circuit for Astable Operation

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TLC552CD	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC552C
TLC552CD.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC552C
TLC552CDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC552C
TLC552CDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLC552C
TLC552CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC552CN
TLC552CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLC552CN

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

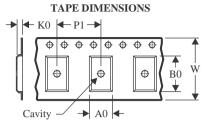
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PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

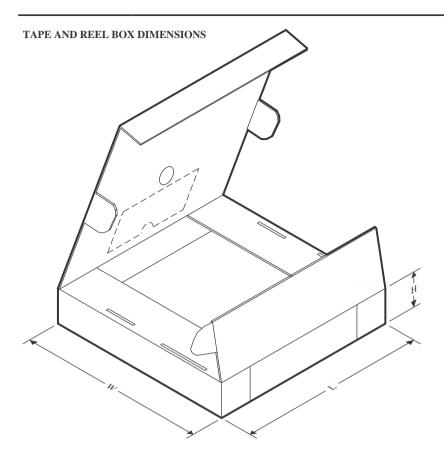


*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC552CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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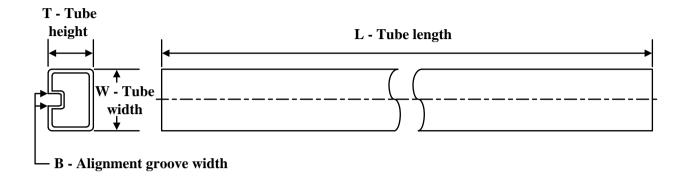
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC552CDR	SOIC	D	14	2500	350.0	350.0	43.0

PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TLC552CD	D	SOIC	14	50	505.46	6.76	3810	4
TLC552CD.A	D	SOIC	14	50	505.46	6.76	3810	4
TLC552CN	N	PDIP	14	25	506	13.97	11230	4.32
TLC552CN.A	N	PDIP	14	25	506	13.97	11230	4.32

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